NSN 5961-01-222-8265

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-222-8265 **Inclosure Material:** Metal **Overall Length:** 0.650 inches **Overall Diameter:** 0.195 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 6.0 inflection-point voltage **Current Rating Per Characteristic:** 220.00 milliamperes source cutoff current megawatts **Special Features:** Junction pattern arrangement: pnpnp **Terminal Type And Quantity:** 2 ribbon and 1 knife blade Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0